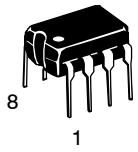
Single Low Noise Operational Amplifier

NE5534, SA5534, SE5534, NE5534A, SA5534A, SE5534A

SOIC−8
D SUFFIX
CASE 751−07



PDIP−8
N SUFFIX
CASE 626−05

The NE/SA/SE5534/5534A are single high−performance low noise operational amplifiers. Compared to other operational amplifiers, such as TL083, they show better noise performance, improved output drive capability, and considerably higher small−signal and power bandwidths.

This makes the devices especially suitable for application in high quality and professional audio equipment, in instrumentation and control circuits and telephone channel amplifiers. The op amps are internally compensated for gain equal to, or higher than, three. The frequency response can be optimized with an external compensation capacitor for various applications (unity gain amplifier, capacitive load, slew rate, low overshoot, etc.).

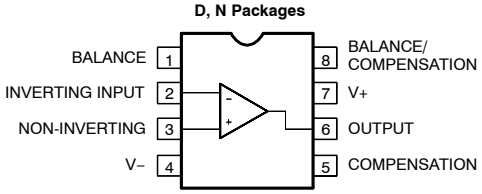
Features

- Small−Signal Bandwidth: 10 MHz
- Output Drive Capability: 600 Ω, 10 V_{RMS} at $V_S = \pm 18$ V
- Input Noise Voltage: 4 nV/$\sqrt{Hz}$
- DC Voltage Gain: 100000
- AC Voltage Gain: 6000 at 10 kHz
- Power Bandwidth: 200 kHz
- Slew Rate: 13 V/μs
- Large Supply Voltage Range: ±3.0 to ±20 V
- Pb−Free Packages are Available

Applications

- Audio Equipment
- Instrumentation and Control Circuits
- Telephone Channel Amplifiers
- Medical Equipment

PIN CONNECTIONS



Top View

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 8 of this data sheet.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 8.

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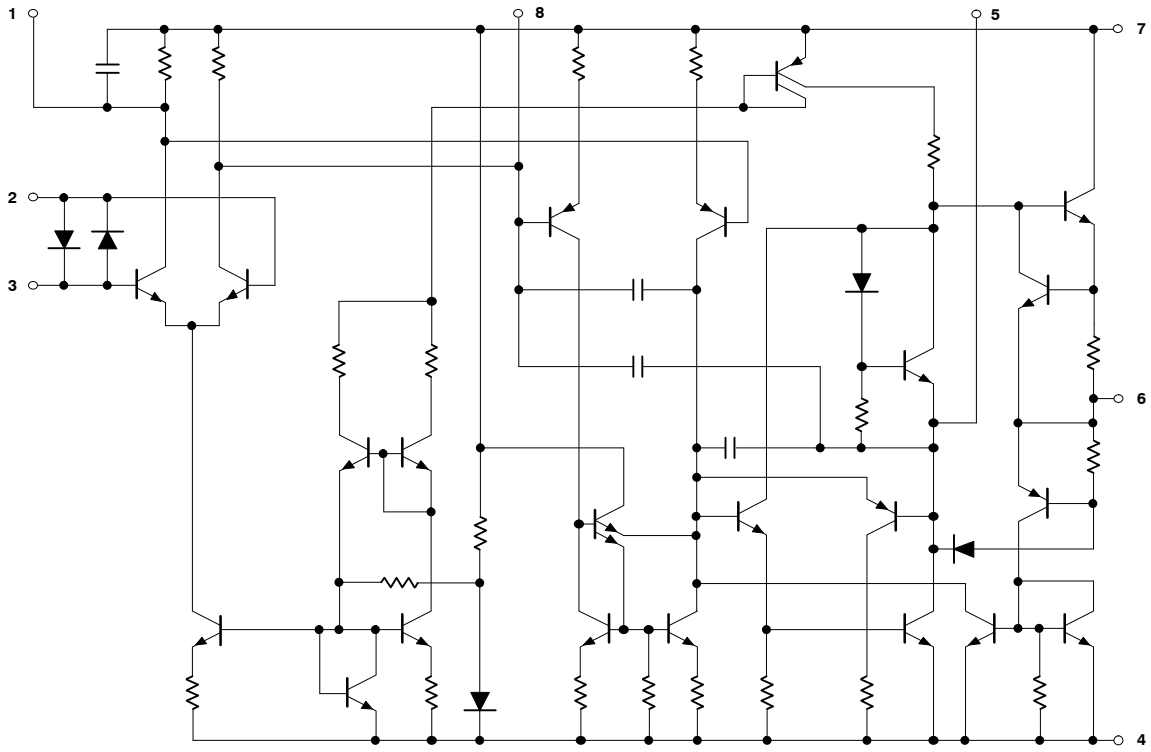

Figure 1. Equivalent Schematic

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V_S	±22	V
Input Voltage	V_{IN}	±V Supply	V
Differential Input Voltage (Note 1)	V_{DIFF}	±0.5	V
Operating Temperature Range NE SA SE	T_{amb}	 0 to +70 −40 to +85 −55 to +125	°C
Storage Temperature Range	T_{stg}	−65 to +150	°C
Junction Temperature	T_j	150	°C
Power Dissipation at 25°C N Package D Package	P_D	 1150 750	mW
Thermal Resistance, Junction−to−Ambient N Package D Package	$R_{\theta JA}$	 130 158	°C/W
Output Short-Circuit Duration (Note 2)	–	Indefinite	–
Lead Soldering Temperature (10 sec max)	T_{sld}	230	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Diodes protect the inputs against overvoltage. Therefore, unless current-limiting resistors are used, large currents will flow if the differential input voltage exceeds 0.6 V. Maximum current should be limited to ±10 mA.
2. Output may be shorted to ground at V_S = ±15 V, T_{amb} = 25°C. Temperature and/or supply voltages must be limited to ensure dissipation rating is not exceeded.

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DC ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C; V_S = ±15 V, unless otherwise noted.) (Notes 3, 4 and 5)

Characteristic	Symbol	Test Conditions	NE/SA5534/5534A			SE5534/5534A			Unit
			Min	Typ	Max	Min	Typ	Max	
Offset Voltage	V_{OS}		–	0.5	4.0	–	0.5	2.0	mV
		Overtemperature	–	–	5.0	–	–	3.0	mV
	$\Delta V_{OS}/\Delta T$		–	5.0	–	–	5.0	–	μV/°C
Offset Current	I_{OS}		–	20	300	–	10	200	nA
		Overtemperature	–	–	400	–	–	500	nA
	$\Delta I_{OS}/\Delta T$		–	200	–	–	200	–	pA/°C
Input Current	I_B		–	500	1500	–	400	800	nA
		Overtemperature	–	–	2000	–	–	1500	nA
	$\Delta I_B/\Delta T$		–	5.0	–	–	5.0	–	nA/°C
Supply Current	I_{CC}		–	4.0	8.0	–	4.0	6.5	mA
Per Op Amp		Overtemperature	–	–	10	–	–	9.0	
Common Mode Input Range	V_{CM}		±12	±13	–	±12	±13	–	V
Common Mode Rejection Ratio	CMRR		70	100	–	80	100	–	dB
Power Supply Rejection Ratio	PSRR		–	10	100	–	10	50	μV/V
Large-Signal Voltage Gain	A_{VOL}	$R_L \geq 600\ \Omega$, V_O = ±10 V	25	100	–	50	100	–	V/mV
		Overtemperature	15	–	–	25	–	–	
Output Swing	V_{OUT}	$R_L \geq 600\ \Omega$	±12	±13	–	±12	±13	–	V
		Overtemperature	±10	±12	–	±10	±12	–	
		$R_L \geq 600\ \Omega$; V_S = ±18 V	±15	±16	–	±15	16	–	
		$R_L \geq 2.0\ k\Omega$	±13	±13.5	–	±13	±13.5	–	
		Overtemperature	±12	±12.5	–	±12	±12.5	–	
Input Resistance	R_{IN}		30	100	–	50	100	–	kΩ
Output Short Circuit Current	I_{SC}		–	38	–	–	38	–	mA

3. For NE5534/5534A, T_{MIN} = 0°C, T_{MAX} = 70°C.
4. For SA5534/5534A, T_{MIN} = −40°C, T_{MAX} = +85°C.
5. For SE5534/5534A, T_{MIN} = −55°C, T_{MAX} = +125°C.

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AC ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C; V_S = ±15 V, unless otherwise noted.)

Characteristic	Symbol	Test Conditions	NE/SA5534/5534A			SE5534/5534A			Unit
			Min	Typ	Max	Min	Typ	Max	
Output Resistance	R_{OUT}	A_V = 30 dB closed-loop f = 10 kHz; R_L = 600 Ω; C_C = 22 pF	–	0.3	–	–	0.3	–	Ω
Transient Response		Voltage-follower, V_{IN} = 50 mV R_L = 600 Ω, C_C = 22 pF, C_L = 100 pF							
Rise Time	t_R		–	20	–	–	20	–	ns
Overshoot	–		–	20	–	–	20	–	%
Transient Response		V_{IN} = 50 mV, R_L = 600 Ω, C_C = 47 pF, C_L = 500 pF							
Rise Time	t_R		–	50	–	–	50	–	ns
Overshoot	–		–	35	–	–	35	–	%
Gain	A_V	f = 10 kHz, C_C = 0 f = 10 kHz, C_C = 22 pF	– –	6.0 2.2	– –	– –	6.0 2.2	– –	V/mV
Gain Bandwidth Product	GBW	C_C = 22 pF, C_L = 100 pF	–	10	–	–	10	–	MHz
Slew Rate	SR	C_C = 0 C_C = 22 pF	– –	13 6.0	– –	– –	13 6.0	– –	V/μs
Power Bandwidth	–	V_{OUT} = ±10 V, C_C = 0 pF V_{OUT} = ±10 V, C_C = 22 pF V_{OUT} = ±14 V, R_L = 600 Ω, C_C = 22 pF, V_{CC} = ±18 V	– – –	200 95 70	– – –	– – –	200 95 70	– – –	kHz

ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C; V_S = 15 V, unless otherwise noted.)

Characteristic	Symbol	Test Conditions	NE/SA/SE5534			NE/SA/SE5534A			Unit
			Min	Typ	Max	Min	Typ	Max	
Input Noise Voltage	V_{NOISE}	f_O = 30 Hz f_O = 1.0 kHz	– –	7.0 4.0	– –	– –	5.5 3.5	7.0 4.5	nV/√Hz
Input Noise Current	I_{NOISE}	f_O = 30 Hz f_O = 1.0 kHz	– –	2.5 0.6	– –	– –	1.5 0.4	– –	pA/√Hz
Broadband Noise Figure	–	f = 10 Hz to 20 kHz; R_S = 5.0 kΩ	–	–	–	–	0.9	–	dB
Channel Separation	–	f = 1.0 kHz; R_S = 5.0 kΩ	–	110	–	–	110	–	dB

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TYPICAL PERFORMANCE CHARACTERISTICS

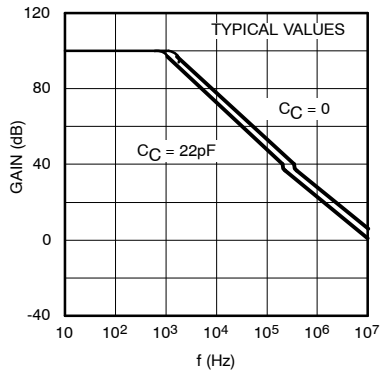

Figure 2. Open-Loop Frequency Response

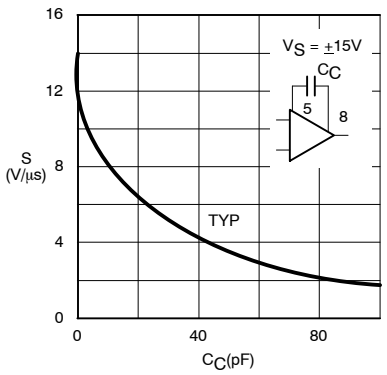

Figure 3. Slew Rate as a Function of Compensation Capacitance

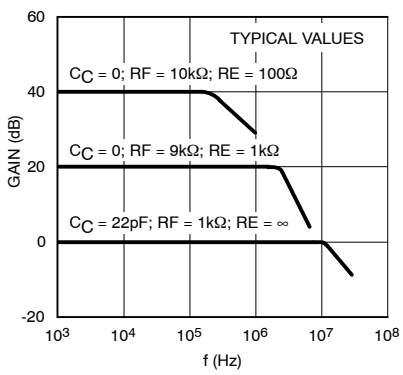

Figure 4. Closed−Loop Frequency Response

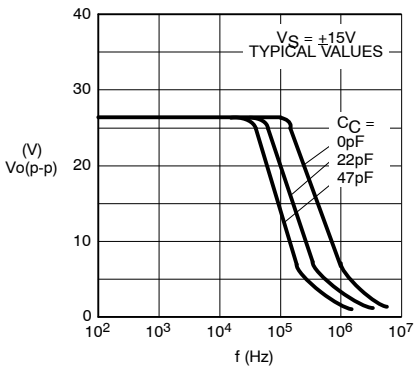

Figure 5. Large−Signal Frequency Response

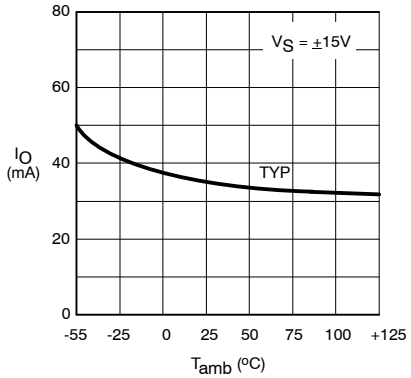

Figure 6. Output Short−Circuit Current

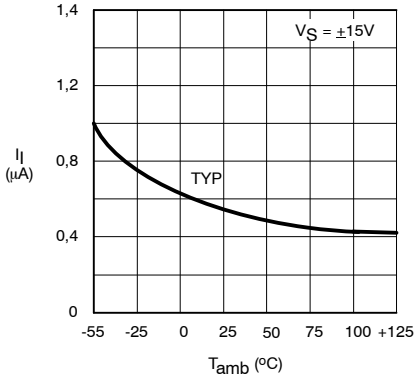

Figure 7. Input Bias Current

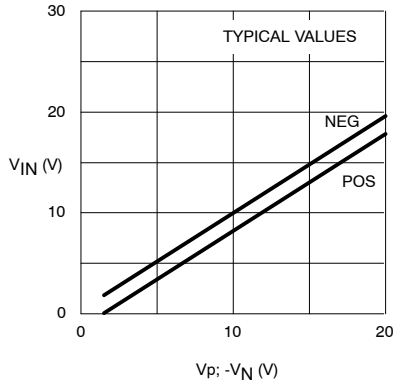

Figure 8. Input Common−Mode Voltage Range

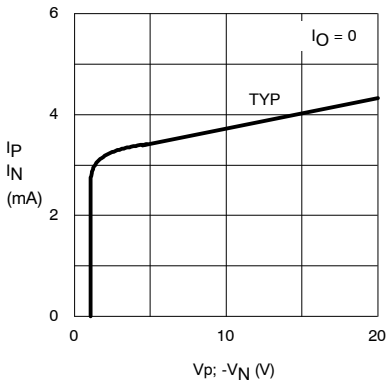

Figure 9. Supply Current Per Op Amp

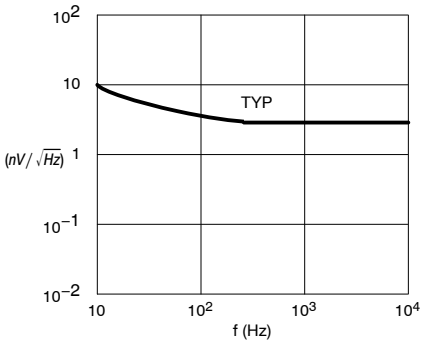

Figure 10. Input Noise Voltage Density

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TYPICAL PERFORMANCE CHARACTERISTICS

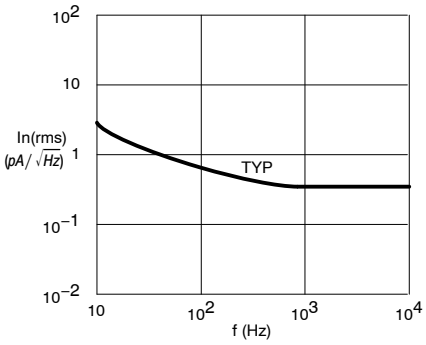

Figure 11. Input Noise Current Density

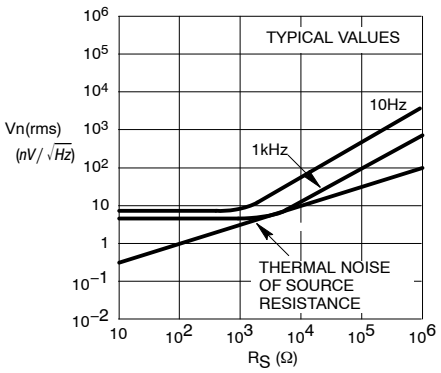

Figure 12. Total Input Noise Density

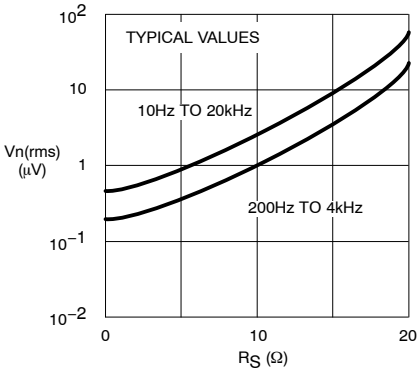

Figure 13. Broadband Input Noise Voltage

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TEST LOAD CIRCUITS

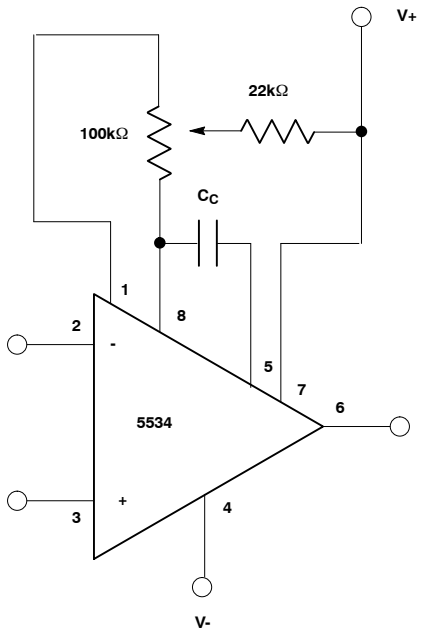

Figure 14. Frequency Compensation and Offset Voltage Adjustment Circuit

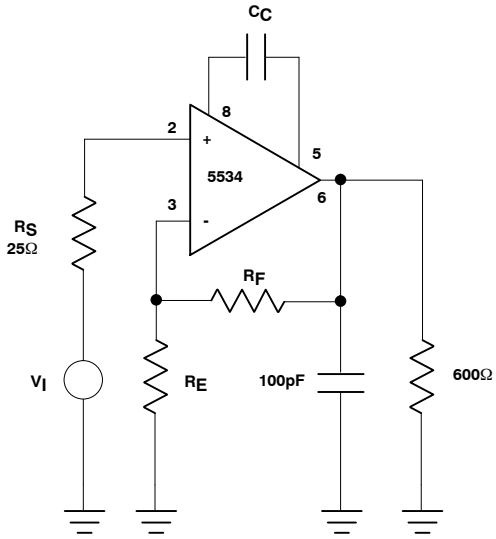

Figure 15. Closed-Loop Frequency Response

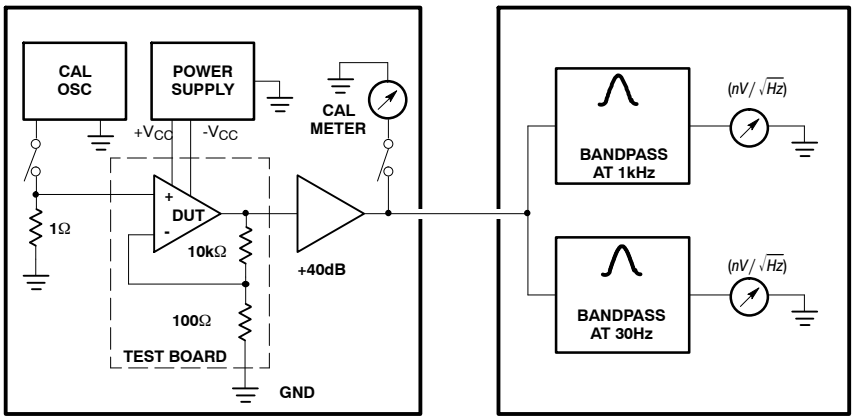

Figure 16. Noise Test Block Diagram

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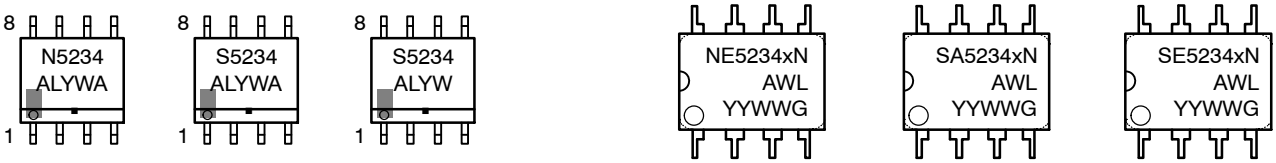
MARKING DIAGRAMS



SOIC−8
D SUFFIX
CASE 751

PDIP−8
N SUFFIX
CASE 626

x = Blank or A
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G or ▪ = Pb−Free Package

ORDERING INFORMATION

Device	Description	Temperature Range	Shipping†
SA5534ADR2G	8−Pin Plastic Small Outline (SO−8) Package (Pb−Free)	−40 to +85°C	2500 / Tape & Reel

DISCONTINUED (Note 6)

NE5534AD	8−Pin Plastic Small Outline (SO−8) Package	0 to +70°C	98 Units / Rail
NE5534ADG	8−Pin Plastic Small Outline (SO−8) Package (Pb−Free)	0 to +70°C	98 Units / Rail
NE5534ADR2	8−Pin Plastic Small Outline (SO−8) Package	0 to +70°C	2500 / Tape & Reel
NE5534ADR2G	8−Pin Plastic Small Outline (SO−8) Package (Pb−Free)	0 to +70°C	2500 / Tape & Reel
NE5534AN	8−Pin Plastic Dual In−Line Package (PDIP−8)	0 to +70°C	50 Units / Rail
NE5534ANG	8−Pin Plastic Dual In−Line Package (PDIP−8) (Pb−Free)	0 to +70°C	50 Units / Rail
NE5534D	8−Pin Plastic Small Outline (SO−8) Package	0 to +70°C	98 Units / Rail
NE5534DG	8−Pin Plastic Small Outline (SO−8) Package (Pb−Free)	0 to +70°C	98 Units / Rail
NE5534DR2	8−Pin Plastic Small Outline (SO−8) Package	0 to +70°C	2500 / Tape & Reel
NE5534DR2G	8−Pin Plastic Small Outline (SO−8) Package (Pb−Free)	0 to +70°C	2500 / Tape & Reel
NE5534N	8−Pin Plastic Dual In−Line Package (PDIP−8)	0 to +70°C	50 Units / Rail
NE5534NG	8−Pin Plastic Dual In−Line Package (PDIP−8) (Pb−Free)	0 to +70°C	50 Units / Rail
SA5534AD	8−Pin Plastic Small Outline (SO−8) Package	−40 to +85°C	98 Units / Rail
SA5534ADG	8−Pin Plastic Small Outline (SO−8) Package (Pb−Free)	−40 to +85°C	98 Units / Rail
SA5534ADR2	8−Pin Plastic Small Outline (SO−8) Package	−40 to +85°C	2500 / Tape & Reel
SA5534AN	8−Pin Plastic Dual In−Line Package (PDIP−8)	−40 to +85°C	50 Units / Rail
SA5534ANG	8−Pin Plastic Dual In−Line Package (PDIP−8) (Pb−Free)	−40 to +85°C	50 Units / Rail
SA5534N	8−Pin Plastic Dual In−Line Package (PDIP−8)	−40 to +85°C	50 Units / Rail
SA5534NG	8−Pin Plastic Dual In−Line Package (PDIP−8) (Pb−Free)	−40 to +85°C	50 Units / Rail
SE5534AN	8−Pin Plastic Dual In−Line Package (PDIP−8)	−55 to +125°C	50 Units / Rail
SE5534ANG	8−Pin Plastic Dual In−Line Package (PDIP−8) (Pb−Free)	−55 to +125°C	50 Units / Rail
SE5534N	8−Pin Plastic Dual In−Line Package (PDIP−8)	−55 to +125°C	50 Units / Rail
SE5534NG	8−Pin Plastic Dual In−Line Package (PDIP−8) (Pb−Free)	−55 to +125°C	50 Units / Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

6. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

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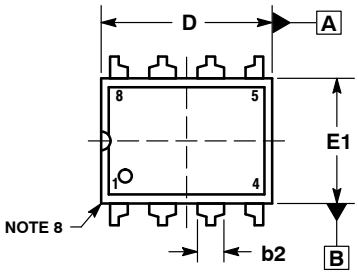
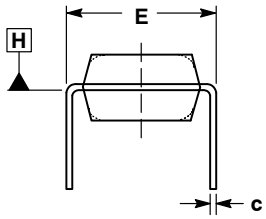
PDIP−8
CASE 626−05
ISSUE P

DATE 22 APR 2015

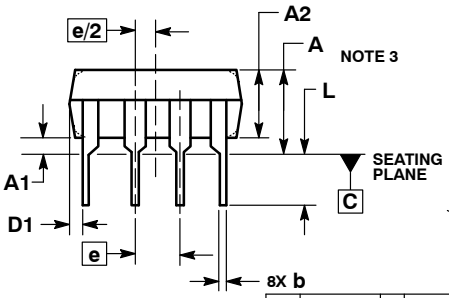
SCALE 1:1



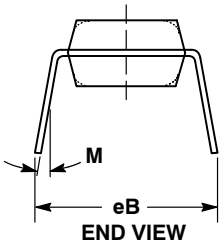
TOP VIEW



END VIEW
WITH LEADS CONSTRAINED
NOTE 5



SIDE VIEW



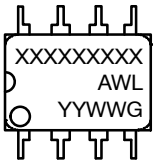
END VIEW
NOTE 6

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS−3.
4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
7. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
8. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	----	0.210	---	5.33
A1	0.015	----	0.38	---
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060 TYP		1.52 TYP	
C	0.008	0.014	0.20	0.36
D	0.355	0.400	9.02	10.16
D1	0.005	----	0.13	---
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
e	0.100 BSC		2.54 BSC	
eB	----	0.430	---	10.92
L	0.115	0.150	2.92	3.81
M	----	10°	---	10°

STYLE 1:
PIN 1. AC IN
2. DC + IN
3. DC − IN
4. AC IN
5. GROUND
6. OUTPUT
7. AUXILIARY
8. V_{CC}

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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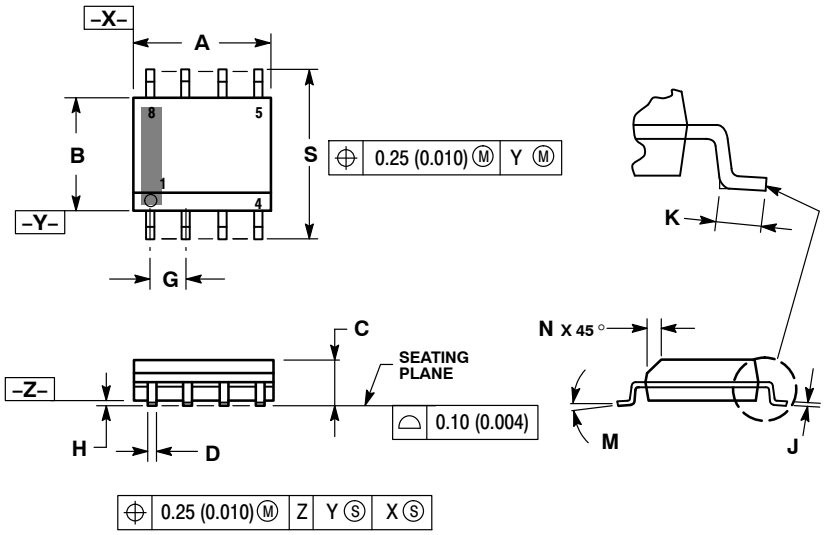
SCALE 1:1

SOIC−8 NB
CASE 751−07
ISSUE AK

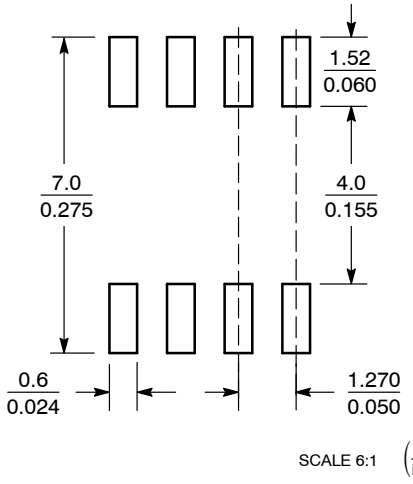
DATE 16 FEB 2011



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751−01 THRU 751−06 ARE OBSOLETE. NEW STANDARD IS 751−07.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

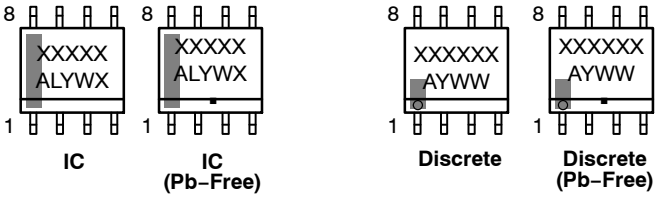
SOLDERING FOOTPRINT*



SCALE 6:1 (mm / inches)

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb−Free Package

XXXXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SOIC−8 NB
CASE 751−07
ISSUE AK

DATE 16 FEB 2011

STYLE 1:
PIN 1. EMITTER
2. COLLECTOR
3. COLLECTOR
4. EMITTER
5. EMITTER
6. BASE
7. BASE
8. EMITTER

STYLE 2:
PIN 1. COLLECTOR, DIE, #1
2. COLLECTOR, #1
3. COLLECTOR, #2
4. COLLECTOR, #2
5. BASE, #2
6. EMITTER, #2
7. BASE, #1
8. EMITTER, #1

STYLE 3:
PIN 1. DRAIN, DIE #1
2. DRAIN, #1
3. DRAIN, #2
4. DRAIN, #2
5. GATE, #2
6. SOURCE, #2
7. GATE, #1
8. SOURCE, #1

STYLE 4:
PIN 1. ANODE
2. ANODE
3. ANODE
4. ANODE
5. ANODE
6. ANODE
7. ANODE
8. COMMON CATHODE

STYLE 5:
PIN 1. DRAIN
2. DRAIN
3. DRAIN
4. DRAIN
5. GATE
6. GATE
7. SOURCE
8. SOURCE

STYLE 6:
PIN 1. SOURCE
2. DRAIN
3. DRAIN
4. SOURCE
5. SOURCE
6. GATE
7. GATE
8. SOURCE

STYLE 7:
PIN 1. INPUT
2. EXTERNAL BYPASS
3. THIRD STAGE SOURCE
4. GROUND
5. DRAIN
6. GATE 3
7. SECOND STAGE Vd
8. FIRST STAGE Vd

STYLE 8:
PIN 1. COLLECTOR, DIE #1
2. BASE, #1
3. BASE, #2
4. COLLECTOR, #2
5. COLLECTOR, #2
6. EMITTER, #2
7. EMITTER, #1
8. COLLECTOR, #1

STYLE 9:
PIN 1. EMITTER, COMMON
2. COLLECTOR, DIE #1
3. COLLECTOR, DIE #2
4. EMITTER, COMMON
5. EMITTER, COMMON
6. BASE, DIE #2
7. BASE, DIE #1
8. EMITTER, COMMON

STYLE 10:
PIN 1. GROUND
2. BIAS 1
3. OUTPUT
4. GROUND
5. GROUND
6. BIAS 2
7. INPUT
8. GROUND

STYLE 11:
PIN 1. SOURCE 1
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN 2
6. DRAIN 2
7. DRAIN 1
8. DRAIN 1

STYLE 12:
PIN 1. SOURCE
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

STYLE 13:
PIN 1. N.C.
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

STYLE 14:
PIN 1. N−SOURCE
2. N−GATE
3. P−SOURCE
4. P−GATE
5. P−DRAIN
6. P−DRAIN
7. N−DRAIN
8. N−DRAIN

STYLE 15:
PIN 1. ANODE 1
2. ANODE 1
3. ANODE 1
4. ANODE 1
5. CATHODE, COMMON
6. CATHODE, COMMON
7. CATHODE, COMMON
8. CATHODE, COMMON

STYLE 16:
PIN 1. EMITTER, DIE #1
2. BASE, DIE #1
3. EMITTER, DIE #2
4. BASE, DIE #2
5. COLLECTOR, DIE #2
6. COLLECTOR, DIE #2
7. COLLECTOR, DIE #1
8. COLLECTOR, DIE #1

STYLE 17:
PIN 1. VCC
2. V2OUT
3. V1OUT
4. TXE
5. RXE
6. VEE
7. GND
8. ACC

STYLE 18:
PIN 1. ANODE
2. ANODE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. CATHODE
8. CATHODE

STYLE 19:
PIN 1. SOURCE 1
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN 2
6. MIRROR 2
7. DRAIN 1
8. MIRROR 1

STYLE 20:
PIN 1. SOURCE (N)
2. GATE (N)
3. SOURCE (P)
4. GATE (P)
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

STYLE 21:
PIN 1. CATHODE 1
2. CATHODE 2
3. CATHODE 3
4. CATHODE 4
5. CATHODE 5
6. COMMON ANODE
7. COMMON ANODE
8. CATHODE 6

STYLE 22:
PIN 1. I/O LINE 1
2. COMMON CATHODE/VCC
3. COMMON CATHODE/VCC
4. I/O LINE 3
5. COMMON ANODE/GND
6. I/O LINE 4
7. I/O LINE 5
8. COMMON ANODE/GND

STYLE 23:
PIN 1. LINE 1 IN
2. COMMON ANODE/GND
3. COMMON ANODE/GND
4. LINE 2 IN
5. LINE 2 OUT
6. COMMON ANODE/GND
7. COMMON ANODE/GND
8. LINE 1 OUT

STYLE 24:
PIN 1. BASE
2. EMITTER
3. COLLECTOR/ANODE
4. COLLECTOR/ANODE
5. CATHODE
6. CATHODE
7. COLLECTOR/ANODE
8. COLLECTOR/ANODE

STYLE 25:
PIN 1. VIN
2. N/C
3. REXT
4. GND
5. IOUT
6. IOUT
7. IOUT
8. IOUT

STYLE 26:
PIN 1. GND
2. dv/dt
3. ENABLE
4. ILIMIT
5. SOURCE
6. SOURCE
7. SOURCE
8. VCC

STYLE 27:
PIN 1. ILIMIT
2. OVLO
3. UVLO
4. INPUT+
5. SOURCE
6. SOURCE
7. SOURCE
8. DRAIN

STYLE 28:
PIN 1. SW_TO_GND
2. DASIC_OFF
3. DASIC_SW_DET
4. GND
5. V_MON
6. VBULK
7. VBULK
8. VIN

STYLE 29:
PIN 1. BASE, DIE #1
2. EMITTER, #1
3. BASE, #2
4. EMITTER, #2
5. COLLECTOR, #2
6. COLLECTOR, #2
7. COLLECTOR, #1
8. COLLECTOR, #1

STYLE 30:
PIN 1. DRAIN 1
2. DRAIN 1
3. GATE 2
4. SOURCE 2
5. SOURCE 1/DRAIN 2
6. SOURCE 1/DRAIN 2
7. SOURCE 1/DRAIN 2
8. GATE 1

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